# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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# Contact us

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# RFM products are now Murata products.

RO3102A

423.22 MHz

SAW

Resonator

SM5035-4

#### Designed for 433.92 MHz Superheterodyne Receiver LOs

Very Low Series Resistance

Surface-mount Ceramic Case

Quartz Stability



Complies with Directive 2002/95/EC (RoHS)

The RO3102A is a one-port surface-acoustic-wave (SAW) resonator packaged in a surface-mount ceramic case. It provides reliable, fundamental-mode, quartz frequency stabilization of local oscillators operating at 423.22 MHz. The RO3102A is designed for 433.92 MHz superheterodyne receivers using a 10.7 MHz IF. Applications include remote-control and wireless security receivers operating in Europe under ETSI EN 300 220-2.

#### Absolute Maximum Ratings

Rating	Value	Units
CW RF Power Dissipation (See Typical Test Circuit)	+5	dBm
DC Voltage Between Terminals (Observe ESD Precautions)	±30	VDC
Case Temperature	-40 to +85	°C
Soldering Temperature (10 seconds / 5 cycles maximum.)	260	°C

Case remperature		-40 (0 +65		C			
Soldering Temperature (10 seconds / 5 cycles maximum.)		2	60	°C			
Characteristic		Sym	Notes	Minimum	Typical	Maximum	Units
Frequency, +25 °C	Nominal Frequency f <sub>C</sub>	423.145		423.295	MHz		
	Tolerance from 423.220 MHz	$\Delta f_{C}$	2, 3, 4, 5			±75	kHz
Insertion Loss		IL	2, 5, 6		1.0	2.0	dB
Quality Factor	Unloaded Q	Q <sub>U</sub>	5.6.7		16,100		
	50 $\Omega$ Loaded Q	QL			1,800		
Temperature Stability	Turnover Temperature	Т <sub>О</sub>		10	25	40	°C
	Turnover Frequency	f <sub>O</sub>	6, 7, 8		f <sub>C</sub>		
	Frequency Temperature Coefficient	FTC			0.032		ppm/°C <sup>2</sup>
Frequency Aging	Absolute Value during the First Year	f <sub>A</sub>	1, 6		10		ppm/yr
DC Insulation Resistance be	tween Any Two Terminals		5	1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R <sub>M</sub>			13		Ω
	Motional Inductance	L <sub>M</sub>	5, 6, 7, 9		87.8		μH
	Motional Capacitance	C <sub>M</sub>			1.6		fF
	Shunt Static Capacitance	CO	5, 6, 9	1.5	1.8	2.1	pF
Test Fixture Shunt Inductance	e	L <sub>TEST</sub>	2, 7		75		nH
Lid Symbolization				8		8	

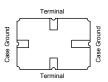
# CAUTION: Electrostatic Sensitive Device. Observe precautions for handling. NOTES:

- Frequency aging is the change in f<sub>C</sub> with time and is specified at +65 °C or 1. less. Aging may exceed the specification for prolonged temperatures above +65 °C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
- 2. The center frequency, f<sub>C</sub>, is measured at the minimum insertion loss point, IL\_MIN, with the resonator in the 50  $\Omega$  test system (VSWR  $\leq$  1.2:1). The shunt inductance,  $L_{\text{TEST}}$  is tuned for parallel resonance with  $C_{\text{O}}$  at  $f_{\text{C}}.$ Typically, fOSCILLATOR or fTRANSMITTER is approximately equal to the resonator f<sub>C</sub>.
- One or more of the following United States patents apply: 4,454,488 and 3 4 616 197
- Typically, equipment utilizing this device requires emissions testing and 4. government approval, which is the responsibility of the equipment manufacturer
- 5. Unless noted otherwise, case temperature T<sub>C</sub> = +25  $\pm$  2 °C.
- 6. The design, manufacturing process, and specifications of this device are subject to change without notice.
- 7. Derived mathematically from one or more of the following directly measured parameters:  $f_C$ , IL, 3 dB bandwidth,  $f_C$  versus  $T_C$ , and  $C_O$ .

- Turnover temperature, T<sub>O</sub>, is the temperature of maximum (or turnover) 8. frequency,  $f_O$ . The nominal frequency at any case temperature,  $T_C$ , may be calculated from:  $f = f_0 [1 - FTC (T_0 - T_C)^2]$ . Typically oscillator  $T_0$  is approximately equal to the specified resonator To.
- 9. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance Co is the static (nonmotional) capacitance between the two terminals measured at low frequency (10 MHz) with a capacitance meter. The measurement includes parasitic capacitance with "NC" pads unconnected. Case parasitic capacitance is approximately 0.05 pF\_ Transducer parallel capacitance can by calculated as:  $C_P \approx C_O - 0.05$  pF.

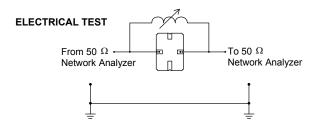
#### **Electrical Connections**

The SAW resonator is bidirectional and may be installed with either orientation. The two terminals are interchangeable and unnumbered. The callout NC indicates no internal connection. The NC pads assist with mechanical positioning and stability. External grounding of the NC pads is recommended to help reduce parasitic capacitance in the circuit.

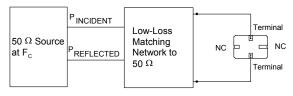


## **Typical Test Circuit**

The test circuit inductor, L<sub>TEST</sub>, is tuned to resonate with the static capacitance, C<sub>O</sub>, at F<sub>C</sub>.



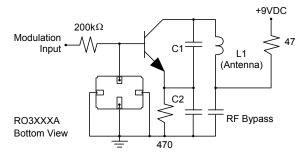
#### POWER TEST



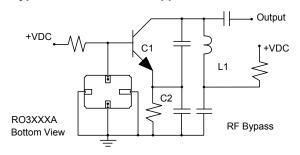
PINCIDENT - P REFLECTED CW RF Power Dissipation =

#### Typical Application Circuits

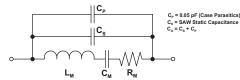
#### **Typical Low-Power Transmitter Application**



#### **Typical Local Oscillator Applications**

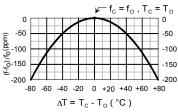


#### **Equivalent RLC Model**

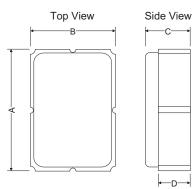


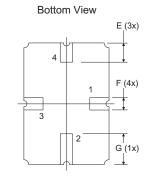
#### **Temperature Characteristics**

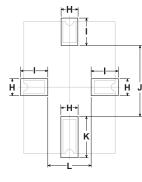
The curve shown on the right accounts for resonator contribution only and does not include LC component temperature contributions.











-D

С

**PCB Land Pattern** Top View

Dimensions	Millimeters			Inches			
Dimensions	Min	Nom	Max	Min	Nom	Мах	
A	4.87	5.00	5.13	0.191	0.196	0.201	
В	3.37	3.50	3.63	0.132	0.137	0.142	
С	1.45	1.53	1.60	0.057	0.060	0.062	
D	1.35	1.43	1.50	0.040	0.057	0.059	
E	0.67	0.80	0.93	0.026	0.031	0.036	
F	0.37	0.50	0.63	0.014	0.019	0.024	
G	1.07	1.20	1.33	0.042	0.047	0.052	
Н	-	1.04	-	-	0.041	-	
I	-	1.46	-	-	0.058	-	
J	-	3.01	-	-	0.119	-	
К	-	1.44	-	-	0.057	-	
L	-	1.92	-	-	0.076	-	

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